

PI6C49CB01J

Industrial Grade 1-to-1 Differential-to-LVCMOS/LVTTL Translator

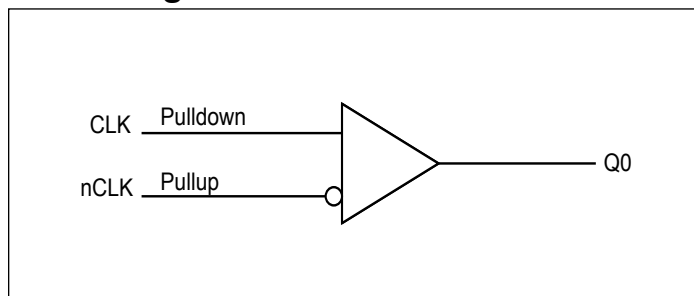
Features

- One LVCMOS/LVTTL output
- Differential CLK/nCLK input pair
- CLK/nCLK pair can accept the following differential input levels: LVPECL, LVDS, LVHSTL, SSTL, HCSL
- Output frequency: 360MHz
- Additive phase jitter, RMS: 0.09ps (typical), 3.3V output
- Full 3.3V and 2.5V operating supply
- -40°C to 105°C ambient operating temperature
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. “Green” Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green):
 - Small 8-pin SOIC(W) package saves board space

Description

The PI6C49CB01J is a industrial grade 1-to-1 Differential-to-LVCMOS/LVTTL Translator High Performance Buffer. The differential input is highly flexible and can accept LVPECL, LVDS, LVHSTL, SSTL, and HCSL. The small 8-lead SOIC footprint makes this device ideal for use in applications with limited board space.

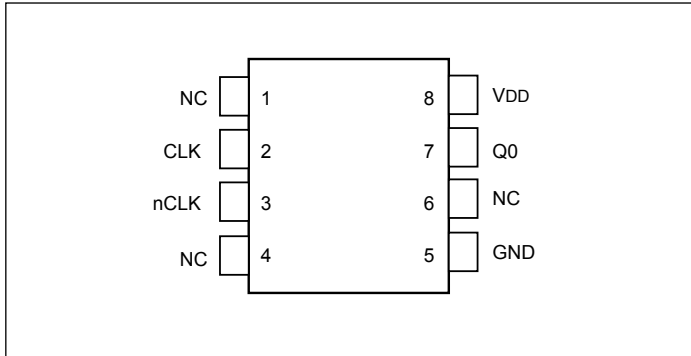
Block Diagram



Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated’s definitions of Halogen- and Antimony-free, “Green” and Lead-free.
3. Halogen- and Antimony-free “Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Configuration



Pin Descriptions

Pin#	Pin Name	Pin Type		Pin Description
1, 4, 6	NC	Unused		No connect.
2	CLK	Input	Pulldown	Non-inverting differential clock input.
3	nCLK	Input	Pullup	Inverting differential clock input.
5	GND	Power		Power supply ground.
7	Q0	Output		Single-ended clock output. LVCMOS/LVTTL interface levels.
8	VDD	Power		Positive supply pin.

Note: *Pullup* and *Pulldown* refer to internal input resistors.

Pin Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
C_{IN}	Input Capacitance			4		pF
R_{PULLUP}	Input Pullup Resistor			51		k Ω
$R_{PULLDOWN}$	Input Pulldown Resistor			51		k Ω
C_{PD}	Power Dissipation Capacitance	VDD = 3.6V		23		pF
R_{OUT}	Output Impedance		5	7	13	Ω

Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Supply Voltage, VDD	4.6V
Inputs, V _I	-0.5V to VDD+0.5V
Output, V _O	-0.5V to VDD+0.5V
Storage Temperature, T _{STG}	-65°C to 150°C
ESD Protection (Input)	2000V min (HBM)
Junction Temperature	125°C (Max)

Note:

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the DC Characteristics or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Units
Ambient Operating Temperature	-40		105	°C
Power Supply Voltage (measured in respect to GND)	2.375		3.465	V

DC Electrical Characteristics

Power Supply DC Characteristics, VDD = 3.3V ± 0.3V or 2.5V ± 5%, T_A = -40°C to 105°C

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
VDD	Positive Supply Voltage		3.0	3.3	3.6	V
			2.375	2.5	2.625	V
IDD	Power Supply Current	25MHz, unloaded			25	mA
		250MHz, unloaded			35	mA

LVC MOS / LV TTL DC Characteristics, VDD = 3.3V ± 0.3V or 2.5V ± 5%, T_A = -40°C to 105°C

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{OH}	Output High Voltage ⁽¹⁾	VDD = 3.6V	2.6		3.6	V
		VDD = 2.625V	1.8		2.625	V
V _{OL}	Output Low Voltage ⁽¹⁾	VDD = 3.6V or 2.625V			0.5	V

Note:

1. Outputs terminated with 50Ω to VDD/2.

Differential DC Characteristics, VDD = 3.3V ± 0.3V or 2.5V ± 5%, T_A = -40°C to 105°C

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I _{IH}	Input High Current	nCLK	V _{IN} = VDD = 3.6V or 2.625V		5	μA
		CLK	V _{IN} = VDD = 3.6V or 2.625V		150	μA
I _{IL}	Input Low Current	nCLK	V _{IN} = 0V, VDD = 3.6V or 2.625V	-150		μA
		CLK	V _{IN} = 0V, VDD = 3.6V or 2.625V	-5		μA
V _{PP}	Peak-to-Peak Input Voltage		0.15		1.3	V
V _{CRM}	Common Mode Input Voltage ⁽¹⁾⁽²⁾		GND + 0.5		VDD - 0.85	V

Note:

1. For single ended applications, the maximum input voltage for CLK, nCLK is VDD + 0.3V.

2. Common mode voltage is defined as (V_{IH} + V_{IL})/2.

AC Electrical Characteristics

AC Characteristics, $V_{DD} = 3.3V \pm 0.3V$, $T_A = -40^\circ C$ to $105^\circ C$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
f_{MAX}	Output Frequency		4		360	MHz
t_{PD}	Propagation Delay ⁽¹⁾	$f \leq 350MHz$	1.6	1.8	2.0	ns
$tsk(pp)$	Part-to-Part Skew ⁽²⁾⁽³⁾				500	ps
t_{jit}	Buffer Additive Phase Jitter, RMS	156.25MHz, Integration Range (12kHz – 20MHz)		0.09		ps
		125MHz, Integration Range (12kHz – 20MHz)		0.15		
t_R/t_F	Output Rise/Fall Time	0.8V to 2V	80	250	350	ps
odc	Output Duty Cycle	$f \leq 166MHz$	45	50	55	%
		$166MHz < f \leq 350MHz$	40	50	60	%

- Note:**
- Electrical parameters are guaranteed over the specified ambient operating temperature range. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at f_{MAX} unless noted otherwise.
 - Measured from the differential input crossing point to the output at $V_{DD}/2$.
 - Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DD}/2$.

AC Characteristics, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ C$ to $105^\circ C$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
f_{MAX}	Output Frequency		4		360	MHz
t_{PD}	Propagation Delay ⁽¹⁾	$f \leq 350MHz$	1.9	2.2	2.5	ns
$tsk(pp)$	Part-to-Part Skew ⁽²⁾⁽³⁾				500	ps
t_{jit}	Buffer Additive Phase Jitter, RMS	156.25MHz, Integration Range (12kHz – 20MHz)		0.04		ps
		125MHz, Integration Range (12kHz – 20MHz)		0.14		
t_R/t_F	Output Rise/Fall Time	20% to 80%	180		350	ps
odc	Output Duty Cycle	$f \leq 250MHz$	45	50	55	%
		$250MHz < f \leq 350MHz$	40	50	60	%

- Note:**
- Electrical parameters are guaranteed over the specified ambient operating temperature range. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at f_{MAX} unless noted otherwise.
 - Measured from the differential input crossing point to the output at $V_{DD}/2$.
 - Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DD}/2$.

Application Information

Wiring the differential input to accept single ended levels

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{DD}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{DD} = 3.3V$, V_{REF} should be 1.25V and $R1/R2 = 0.609$.

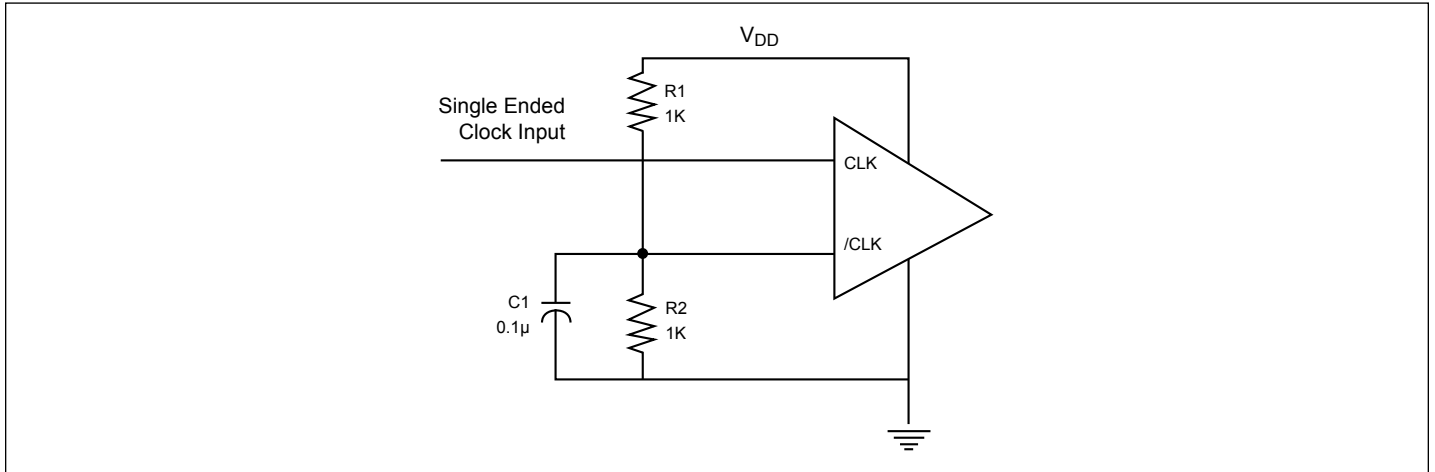


Figure 1. Single-ended Input to Differential Input Device

Thermal Information

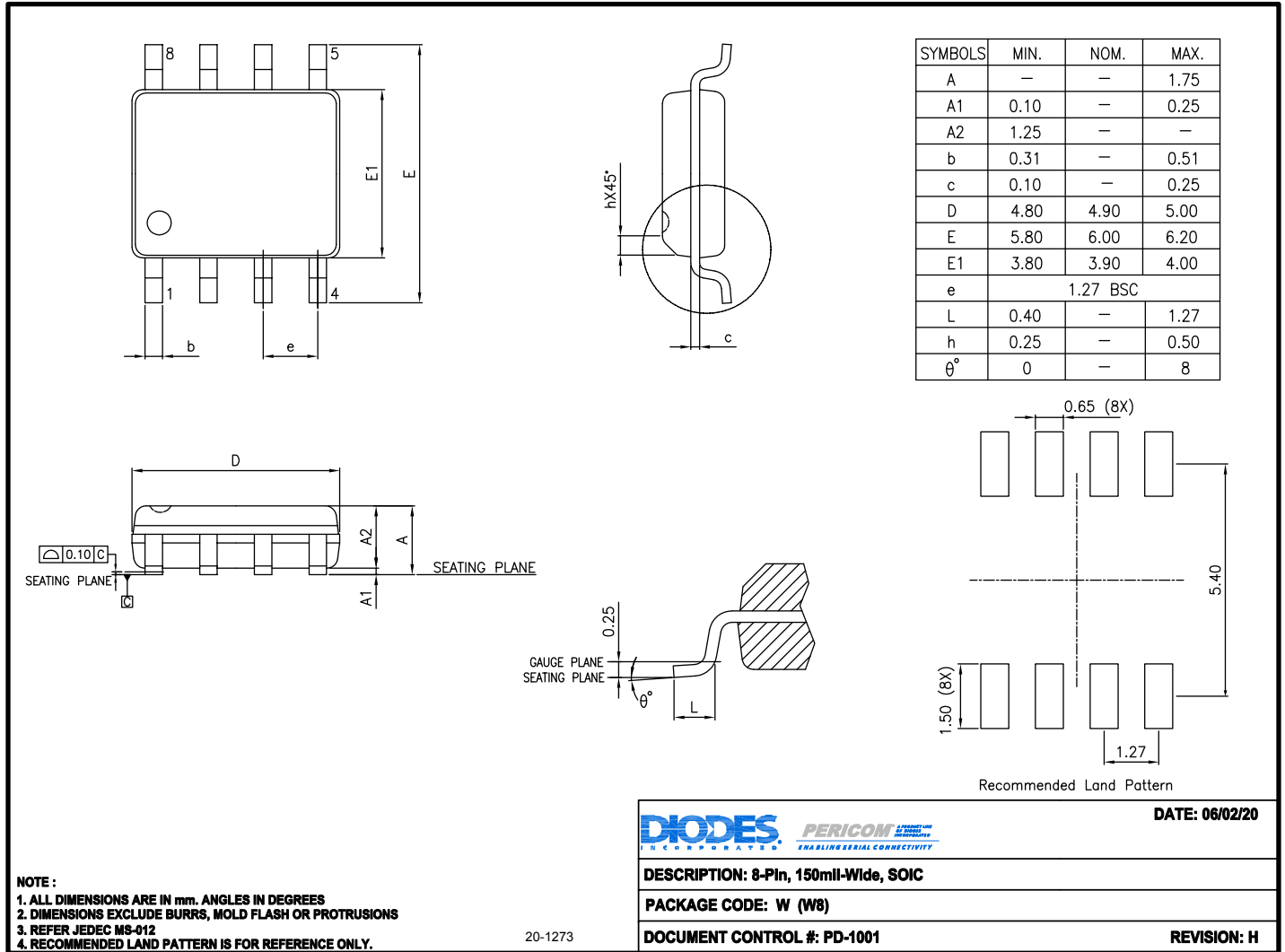
Symbol	Description	Condition	
Θ_{JA}	Junction-to-ambient thermal resistance	Still air	157 °C/W
Θ_{JC}	Junction-to-case thermal resistance		42 °C/W

Part Marking

PI6C49CB
01JWE
YYWWXX

YY: Year
 WW: Workweek
 1st X: Assembly Code
 2nd X: Fab Code

Packaging Mechanical: 8-SOIC (W)



For latest package info.

please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

Ordering Information

Ordering Code	Package Code	Package Description
PI6C49CB01JWEX	W	8-pin, 150mil-Wide (SOIC)

Notes:

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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. J = Industrial Grade
5. E = Pb-free and Green
6. X suffix = Tape/Reel

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